NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

Rev. 11 — 9 December 2011

Product data sheet

1. Product profile

1.1 General description

NPN Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package	-			Package	
	NXP JEITA JEDEC ^{con}		complement	configuration		
PDTC143XE	SOT416	SC-75	-	PDTA143XE	ultra small	
PDTC143XM	SOT883	SC-101	-	PDTA143XM	leadless ultra small	
PDTC143XT	SOT23	-	TO-236AB	PDTA143XT	small	
PDTC143XU	SOT323	SC-70	-	PDTA143XU	very small	

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design

1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified
- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
I _O	output current		-	-	100	mA
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		1.7	2.1	2.6	



NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
SOT23; S	SOT323; SOT416		
1	input (base)	_	
2	GND (emitter)	3	
3	output (collector)	2	1 R1 R2 sym007
SOT883			
1	input (base)		
2	GND (emitter)		
3 output (collector)		2 Transparent top view	1 R1 R2 Sym007

3. Ordering information

Type number	Package	Package					
	Name	Description	Version				
PDTC143XE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTC143XM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883				
PDTC143XT	-	plastic surface-mounted package; 3 leads	SOT23				
PDTC143XU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

4. Marking

Table 5. Marking codes	
Type number	Marking code ^[1]
PDTC143XE	34
PDTC143XM	E2
PDTC143XT	*32
PDTC143XU	*53

[1] * = placeholder for manufacturing site code

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

5. Limiting values

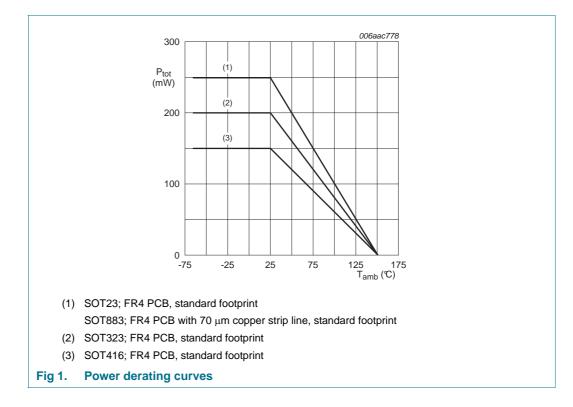
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	7	V
VI	input voltage				
	positive		-	+20	V
	negative		-	-7	V
lo	output current		-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \leq 1 ms$	-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PDTC143XE (SOT416)		<u>[1][2]</u> _	150	mW
	PDTC143XM (SOT883)		[2][3]	250	mW
	PDTC143XT (SOT23)		<u>[1]</u> -	250	mW
	PDTC143XU (SOT323)		<u>[1]</u> -	200	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 µm copper strip line, standard footprint.

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω



6. Thermal characteristics

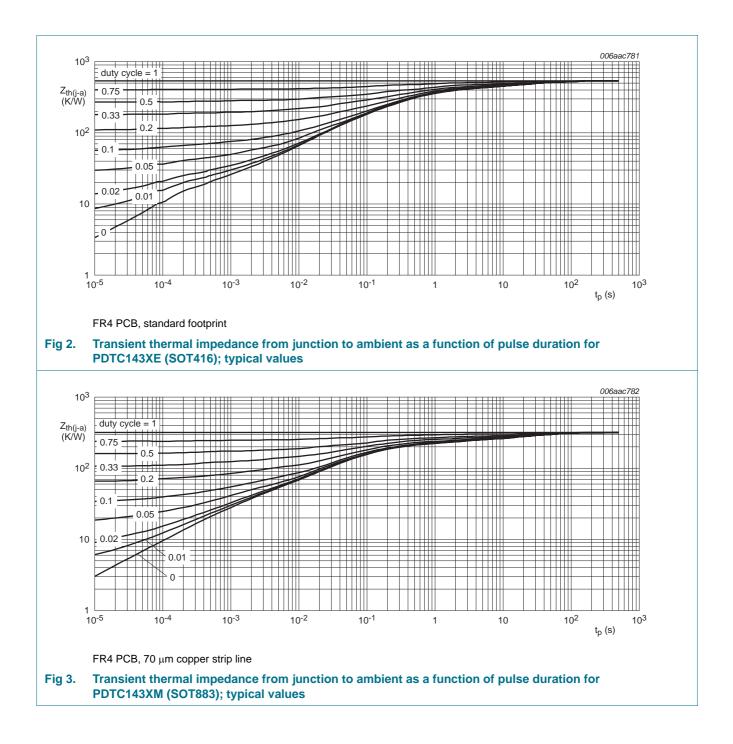
Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	PDTC143XE (SOT416)		[1][2]	-	830	K/W
	PDTC143XM (SOT883)		[2][3]	-	500	K/W
	PDTC143XT (SOT23)		<u>[1]</u> -	-	500	K/W
	PDTC143XU (SOT323)		<u>[1]</u> -	-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

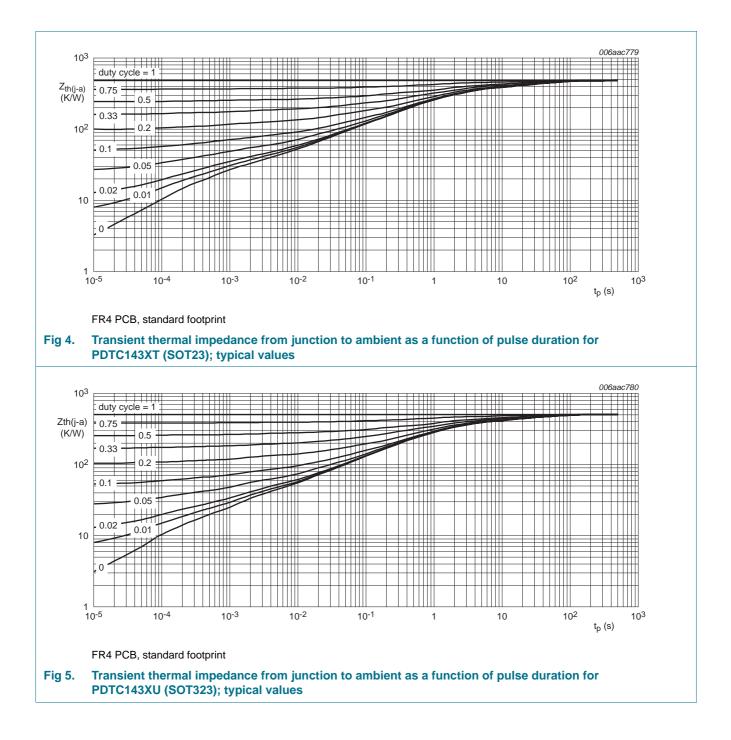
[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 μ m copper strip line, standard footprint.

PDTC143X series



PDTC143X series



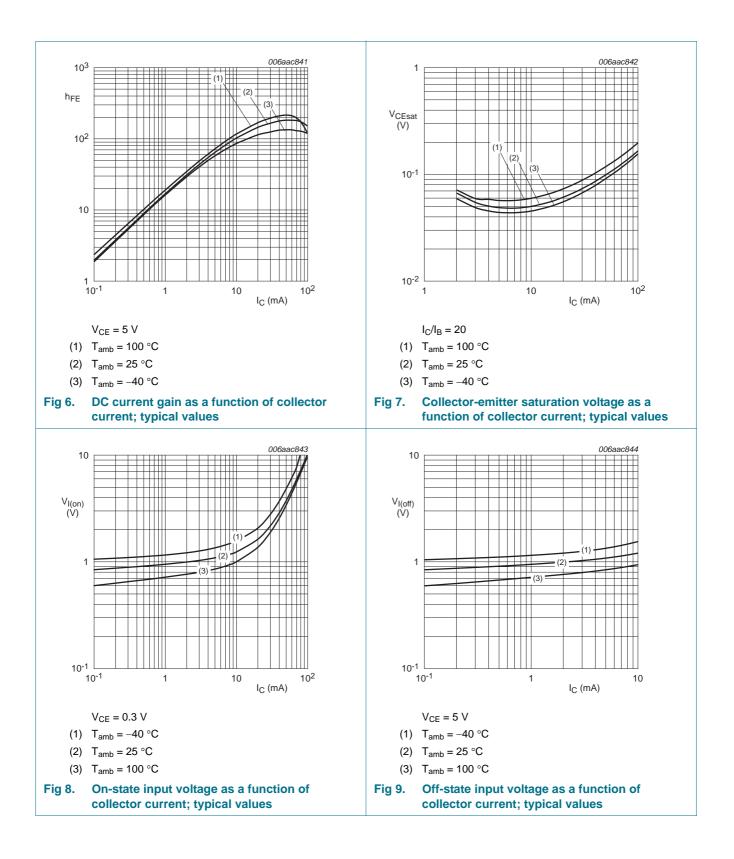
NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$		-	-	100	nA
I _{CEO}	collector-emitter	V_{CE} = 30 V; I_B = 0 A		-	-	1	μA
	cut-off current	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A};$ $T_j = 150 ^{\circ}\text{C}$		-	-	5	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$		-	-	600	μΑ
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$		50	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_{C} = 10 mA; I_{B} = 0.5 mA		-	-	100	mV
V _{I(off)}	off-state input voltage	V_{CE} = 5 V; I_C = 100 μ A		-	0.9	0.3	V
V _{I(on)}	on-state input voltage	V_{CE} = 0.3 V; I_{C} = 20 mA		2.5	1.5	-	V
R1	bias resistor 1 (input)			3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio			1.7	2.1	2.6	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz		-	-	2.5	pF
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz	<u>[1]</u>	-	230	-	MHz

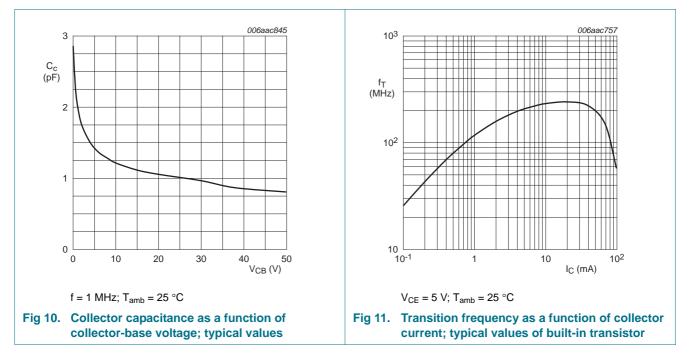
[1] Characteristics of built-in transistor

PDTC143X series



PDTC143X series

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω



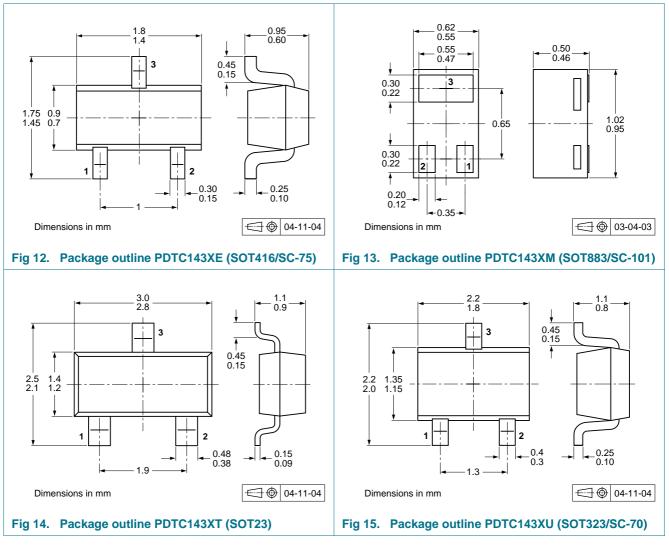
8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

9. Package outline



10. Packing information

Table 9.Packing methods

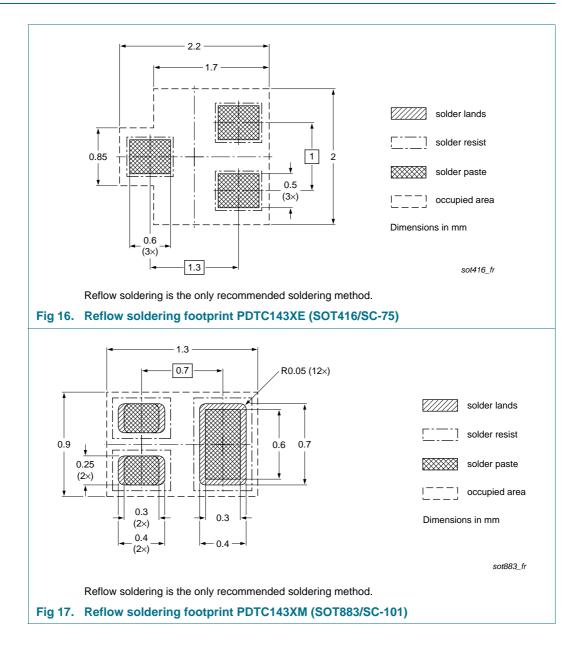
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

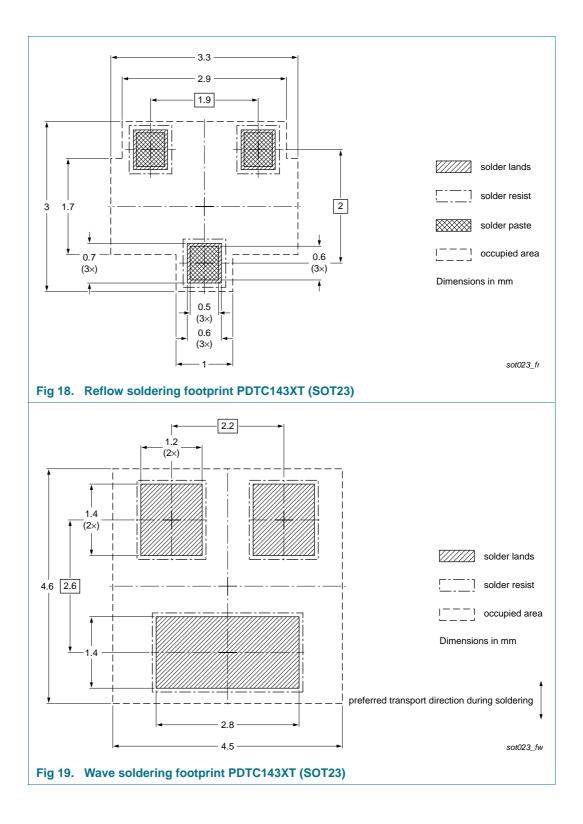
Type number	Package	Description	Packing	Packing quantity		
			3000	5000	10000	
PDTC143XE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTC143XM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTC143XT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
PDTC143XU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	

[1] For further information and the availability of packing methods, see Section 14.

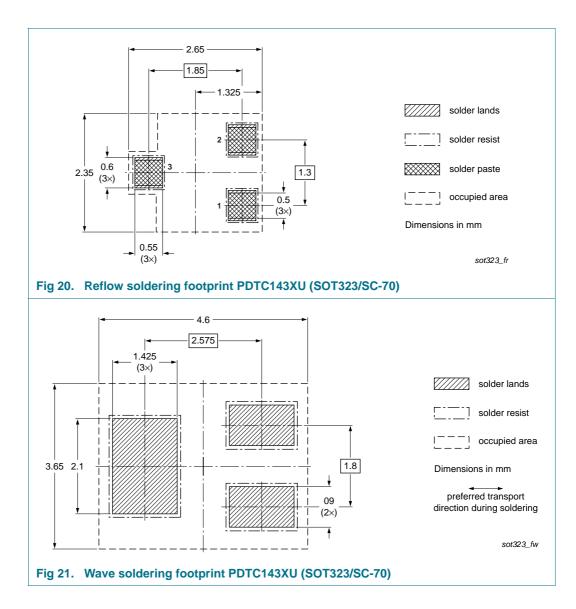
NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

11. Soldering





NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω



NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

12. Revision history

Table 10.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTC143X_SER v.11	20111209	Product data sheet	-	PDTC143X_SERIES v.10
Modifications:	 Type number 	s PDTC143XEF, PDTC1432	XK and PDTC143XS re	emoved.
	Section 1 "Pr	oduct profile": updated		
	 Section 2 "Pir 	nning information": updated		
	 Section 4 "Ma 	arking": updated		
	 Figure 1 to 5, 	10 and 11: added		
	Section 6 "The section of the sec	ermal characteristics": upda	ated	
	 Figure 6 to 9: 	updated		
	• Table 8 "Chai	racteristics": V _{I(on)} and V _{I(off)}	updated, I _{CEO} updated	d, f _T added
	 Section 8 "Te 	st information": added		
	Section 11 "S	oldering": added		
	 Section 13 "L 	egal information": updated		
PDTC143X_SERIES v.10	20091116	Product data sheet	-	PDTC143X_SERIES v.9
PDTC143X_SERIES v.9	20050726	Product data sheet	-	PDTC143X_SERIES v.8
PDTC143X_SERIES v.8	20040806	Product specification	-	PDTC143X_SERIES v.7
PDTC143X_SERIES v.7	20040323	Product specification	-	PDTC143X_SERIES v.6
PDTC143X_SERIES v.6	20040112	Product specification	-	PDTC143X_SERIES v.5
PDTC143X_SERIES v.5	20031112	Product specification	-	PDTC143X_SERIES v.4
PDTC143X_SERIES v.4	20030910	Product specification	-	PDTC143X_SERIES v.3
PDTC143X_SERIES v.3	20030410	Product specification	-	-

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PDTC143X_SER

NPN resistor-equipped transistors; $R1 = 4.7 \text{ k}\Omega$, $R2 = 10 \text{ k}\Omega$

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PDTC143X series

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

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